

In the claims:

Please amend the claims as follows:

1-16. (Cancelled)

17. (Previously Amended) A method of manufacturing a self-light emitting device comprising:

forming an EL element comprising a first electrode, a light emitting layer over the first electrode, and a second electrode over the light emitting layer;

forming a film comprising an inorganic material covering said EL element by using a CVD method or an evaporation method, and

forming a film comprising an organic material covering said film comprising said inorganic material by using an ink jet method.

18. (Previously Amended) A method of manufacturing a self-light emitting device comprising:

forming an EL element comprising a first electrode, a light emitting layer over the first electrode, and a second electrode over the light emitting layer;

forming a film comprising an organic material covering said EL element by using an ink jet method, and

forming a film comprising an inorganic material covering said film comprising said organic material by using a CVD method or an evaporation method.

19. (Currently Amended) A method of manufacturing a self-light emitting device according to claim 17, wherein said ~~EL~~ light emitting layer, said ~~cathode~~ second electrode, said film ~~made of~~ comprising said organic material, and said film ~~made of~~ comprising said inorganic material are formed using the same film deposition apparatus.

20. (Currently Amended) A method of manufacturing a self-light emitting device according to claim 18, wherein said ~~EL~~ light emitting layer, said ~~cathode~~ second electrode, said film ~~made of~~ comprising said organic material, and said film ~~made of~~ comprising said inorganic material are formed using the same film deposition apparatus.

21. (Currently Amended) A method of manufacturing a self-light emitting device according to claim 17, wherein said ~~EL~~ light emitting layer and said film ~~made of~~ comprising said organic material are formed by an electric field application method or an ink jet method.

22. (Currently Amended) A method of manufacturing a self-light emitting device according to claim 18, wherein said ~~EL~~ light emitting layer and said film ~~made of~~ comprising said organic material are formed by an electric field application method or an ink jet method.

23. (Previously Added) A method of manufacturing a light emitting device comprising:

forming an EL element comprising a first electrode, a light emitting layer over the first electrode, and a second electrode over the light emitting layer;

forming a film comprising an inorganic material covering said EL element by using a CVD method or an evaporation method; and

forming a film comprising an organic material covering said film comprising said inorganic material by using an ink jet method,

wherein said light emitting layer, said second electrode, said film comprising an inorganic material, and said film comprising an organic material are formed continuously using the same film deposition apparatus.

24. (Previously Added) A method of manufacturing a light emitting device comprising:  
forming an EL element comprising a first electrode, a light emitting layer over the first electrode, and a second electrode over the light emitting layer;

forming a film comprising an organic material covering said EL element by using an ink jet method; and

forming a film comprising an inorganic material covering said film comprising said organic material by using a CVD method or an evaporation method,

wherein said light emitting layer, said second electrode, said film comprising an inorganic material, and said film comprising an organic material are formed continuously using the same film deposition apparatus.

C<sub>1</sub>  
25. (Currently Amended) A method of manufacturing a light emitting device comprising:

forming an EL element comprising a first electrode, a light emitting layer over the first electrode, and a second electrode over the light emitting layer;

forming a film comprising an inorganic material covering said EL element; and

forming a film comprising an organic material covering said film comprising said inorganic material,

wherein said light emitting layer and said film comprising an organic material are formed ~~using the same film deposition~~ by an ink jet method.

26. (Currently Amended) A method of manufacturing a light emitting device comprising:

forming an EL element comprising a first electrode, a light emitting layer over the first electrode, and a second electrode over the light emitting layer;

forming a film comprising an organic material covering said EL element; and

forming a film comprising an inorganic material covering said film comprising said organic material,

wherein said light emitting layer and said film comprising an ~~inorganic~~ material are formed ~~using the same film deposition~~ by an ink jet method.

C<sub>2</sub>  
27. (New) A method of manufacturing a self-light emitting device comprising:

forming an EL element by an electric field application method, the EL element comprising a first electrode, a light emitting layer over the first electrode, and a second electrode over the light emitting layer;

forming a film comprising an inorganic material covering said EL element by using a CVD method or an evaporation method, and

forming a film comprising an organic material covering said film comprising said inorganic material by an electric field application method.

28. (New) A method of manufacturing a self-light emitting device comprising:

forming an EL element by an electric field application method, the EL element comprising a first electrode, a light emitting layer over the first electrode, and a second electrode over the light emitting layer;

forming a film comprising an organic material covering said EL element by an electric field application method, and

forming a film comprising an inorganic material covering said film comprising said organic material by using a CVD method or an evaporation method.

29. (New) A method of manufacturing a self-light emitting device comprising:

forming an EL element by an electric field application method, the EL element comprising a first electrode, a light emitting layer over the first electrode, and a second electrode over the light emitting layer;

forming a film comprising an inorganic material covering said EL element by using a CVD method or an evaporation method, and

forming a film comprising an organic material covering said film comprising said inorganic material by an electric field application method,

wherein the light emitting layer, the second electrode, the film comprising inorganic material, and the film comprising organic material are formed using the same film deposition apparatus.

30. (New) A method of manufacturing a self-light emitting device comprising:

forming an EL element by an electric field application method, the EL element comprising a first electrode, a light emitting layer over the first electrode, and a second electrode over the light emitting layer;

forming a film comprising an organic material covering said film comprising said inorganic material by an electric field application method; and

forming a film comprising an inorganic material covering said EL element by using a CVD method or an evaporation method,

wherein the light emitting layer, the second electrode, the film comprising inorganic material, and the film comprising organic material are formed using the same film deposition apparatus.

31. (New) A method of manufacturing a self-light emitting device according to claim 27, wherein the film comprising an inorganic material is formed from silicon nitride, tantalum oxide, aluminum nitride, or carbon.

32. (New) A method of manufacturing a self-light emitting device according to claim 28, wherein the film comprising an inorganic material is formed from silicon nitride, tantalum oxide, aluminum nitride, or carbon.

33. (New) A method of manufacturing a self-light emitting device according to claim 29, wherein the film comprising an inorganic material is formed from silicon nitride, tantalum oxide, aluminum nitride, or carbon.

34. (New) A method of manufacturing a self-light emitting device according to claim 30, wherein the film comprising an inorganic material is formed from silicon nitride, tantalum oxide, aluminum nitride, or carbon.

35. (New) A method of manufacturing a self-light emitting device according to claim 27, wherein the film comprising an organic material is formed from polyamide, polyimide, acrylic resin, or benzocyclobuten.

36. (New) A method of manufacturing a self-light emitting device according to claim 28, wherein the film comprising an organic material is formed from polyamide, polyimide, acrylic resin, or benzocyclobuten.

C 2 37. (New) A method of manufacturing a self-light emitting device according to claim 29, wherein the film comprising an organic material is formed from polyamide, polyimide, acrylic resin, or benzocyclobuten.

38. (New) A method of manufacturing a self-light emitting device according to claim 30, wherein the film comprising an organic material is formed from polyamide, polyimide, acrylic resin, or benzocyclobuten.

39. (New) A method of manufacturing a self-light emitting device according to claim 27, wherein the self-light emitting device is incorporated into an electronic appliance selected from the group consisting of a video camera, a head mount type display, an image reproduction apparatus, a portable computer, a personal computer, a portable telephone, and a sound reproduction device.

40. (New) A method of manufacturing a self-light emitting device according to claim 28, wherein the self-light emitting device is incorporated into an electronic appliance selected from the group consisting of a video camera, a head mount type display, an image reproduction

Applicant : Shunpei YAMAZAKI et al  
Serial No. : 09/817,675  
Filed : March 27, 2001  
Page : 6 of 7

Attorney's Docket No.: 12732-024001 / US4798

apparatus, a portable computer, a personal computer, a portable telephone, and a sound reproduction device.

41. (New) A method of manufacturing a self-light emitting device according to claim 29, wherein the self-light emitting device is incorporated into an electronic appliance selected from the group consisting of a video camera, a head mount type display, an image reproduction apparatus, a portable computer, a personal computer, a portable telephone, and a sound reproduction device.

C 2 42. (New) A method of manufacturing a self-light emitting device according to claim 30, wherein the self-light emitting device is incorporated into an electronic appliance selected from the group consisting of a video camera, a head mount type display, an image reproduction apparatus, a portable computer, a personal computer, a portable telephone, and a sound reproduction device.

---